

## DESCRIPTION:

The JST60T-1200BW triac is suitable for general purpose AC switching. It can be used as an ON/OFF function in applications such as heating regulation, induction motor starting circuits, for phase control operation in light dimmers, motor speed controllers. JST60T-1200BW snubberless triac is especially recommended for use on inductive loads. By using a DBC, JST60T-1200BW provides a rated insulation voltage of 2500 VRMS, complying with UL standards (File ref: E252906). Package TG-C is RoHS compliant.



## MAIN FEATURES

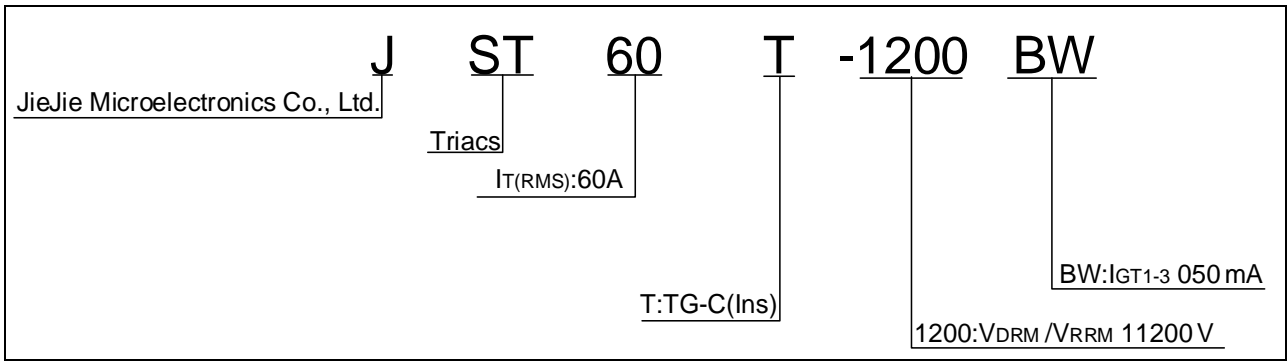
Symbol	Value	Unit
$I_{T(RMS)}$	60	A
$V_{DRM}/V_{RRM}$	1200	V
$I_{GT} / /$	50/50/50	mA

## ABSOLUTE MAXIMUM RATINGS

Parameter	Symbol	Value	Unit
Storage junction temperature range	$T_{stg}$	-40-150	
Operating junction temperature range	$T_j$	-40-125	
Repetitive peak off-state voltage ( $T_j=25^\circ\text{C}$ )	$V_{DRM}$	1200	V
Repetitive peak reverse voltage ( $T_j=25^\circ\text{C}$ )	$V_{RRM}$	1200	V
RMS on-state current ( $T_c 094^\circ\text{C}$ )	$I_{T(RMS)}$	60	A
Non repetitive surge peak on-state current (full cycle, $t_p=20\text{ms}$ , $T_j=25^\circ\text{C}$ )	$I_{TSM}$	600	A
Non repetitive surge peak on-state current (full cycle, $t_p=16.6\text{ms}$ , $T_j=25^\circ\text{C}$ )		660	
$I^2t$ value for fusing ( $t_p=10\text{ms}$ , $T_j=25^\circ\text{C}$ )	$I^2t$	1800	$\text{A}^2\text{s}$
Critical rate of rise of on-state current ( $I_G=2 \times I_{GT}$ , $f=100\text{Hz}$ , $T_j=125^\circ\text{C}$ )	$di/dt$	100	$\text{A/s}$
Peak gate current ( $t_p=20^\circ\text{s}$ , $T_j=125^\circ\text{C}$ )	$I_{GM}$	10	A
Average gate power dissipation ( $T_j=125^\circ\text{C}$ )	$P_{G(AV)}$	0.5	W



ORDERING INFORMATION



MARKING

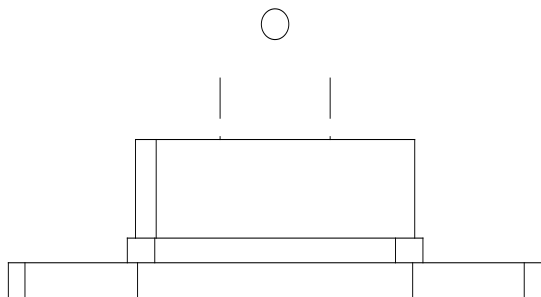
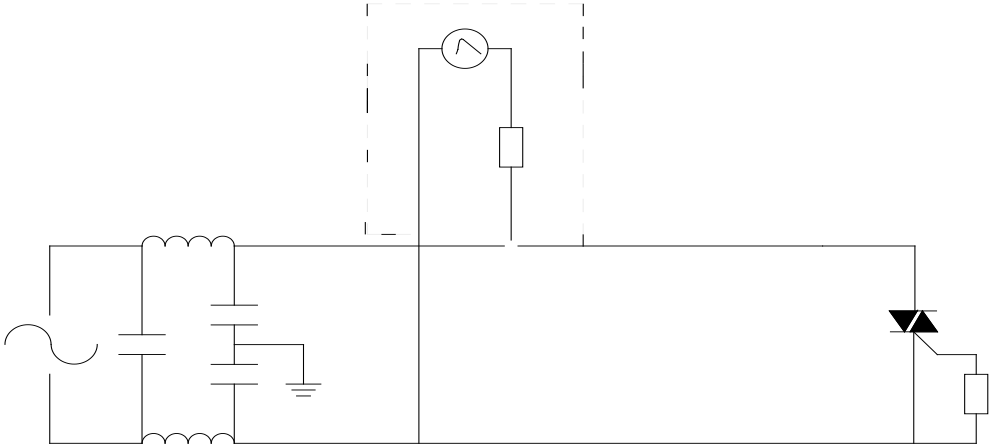


FIG.1: Maximum power dissipation versus RMS  
on-state current

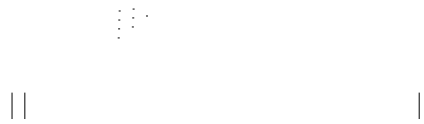
FIG.2:

FIG.7 ÖTest circuit for inductive and resistive loads to IEC-61000-4-5 standards





PACKAGE MECHANICAL DATA



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